

M4127G001					
Sl. No.	ITI Code	Description	Make	MPN	PR Qty
1	SA2G3470001G7D1	TLZ SERIES ZENER DIODE 4.7V, Mini MELF SOD-80	VISHAY INTERT.ASIA(PTE)LTD	TLZ4V7B/ TLZ4V7B-GS18	100
2	SA2D1000532S1D1	COMMON MODE CHOKE, SMD, TVS, ESD SUPPRESSOR, 1 CHANNEL, SGP1917N5 PACKAGE	SEMTECH CORPORATION	ECLAMP8052P.TCT	200
3	SA2D1000558S1D1	TVS DIODE ARRAY, SMD, 4 CHANNEL, SOT563 PACKAGE, LOW CAPACITANCE	LITTLE FUSE FAR EAST PTE.LTD.	SP3003-04XTG	1000
4	SA2D1000553S1D2	DIODE, SMD, TVS, X1SON PACKAGE, -40 TO +125 DEG CEL	TEXAS INSTRUMENTS PVT LTD(NATIONAL SEMICONDUCTOR)	TPD1E10B06DPYT	500
5	SA2B9000555D9D2	DIODE, SMD, SCHOTTKY, BARRIER RECTIFIER, 5A, 40V, SMB (DO-214AA) PACKAGE	Micro Commercial Components	SK54B-LTP	300
6	SA2D1000557S1D2	DIODE, TVS, SMD, 400W, 12V, SMA PACKAGE, -55 TO +150 DEG CEL	DIODES INCORPORATED	SMAJ12CA-13-F	200
7	SA2D1000556S1D2	DIODE, TVS, ESD SUPPRESSOR, 6 CHANNEL, UQFN-10 PACKAGE, -40 TO +85 DEG CEL	TEXAS INSTRUMENTS PVT LTD(NATIONAL SEMICONDUCTOR)	TPD6E001RSER	200
8	SA2B9000556E1D1	DIODE, SMD, SCHOTTKY, BARRIER RECTIFIER, 1A, 40, SMA (DO-214AC) PACKAGE	ROHM Semiconductor Singapore Pte. Ltd.	RB168L-40TFTE25	250
9	SA1C2000506F5D2	TRANSISTOR, MOSFET, DUAL N-CHANNEL, 20V VDS, 19.8A, SOIC-8 PACKAGE, -55 TO +155 DEG CEL	VISHAY INTERT.ASIA(PTE)LTD	SI4204DY-T1-GE3	300
10	SA1B1000506F4D2	Bipolar (BJT) Transistor PNP 40 V 200 mA 250MHz 350 mW Surface Mount SOT-23	CENTRAL SEMICONDUCTOR CORP	CMPT3906G TR PBFREE	200
11	SA1C2000506F4D2	TRANSISTOR, MOSFET, N-CHANNEL, 30V VDS, 3.6A, SOT 23-3 PACKAGE, -55 TO +155 DEG CEL	VISHAY INTERT.ASIA(PTE)LTD	SI2300DS-T1-GE3	200
12	DA2B6000495D5D1	TRIAC, PACKAGE TO-220 AB, -40 TO +150 DEG. C	1. CONTINENTAL DEVICE INDIA LTD. 2. NXP SEMICONDUCTORS (FREESCALE SEMICONDUCTOR) 3. WEEN SEMICONDUCTORS CO LTD	BT136D	100